

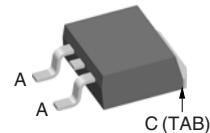
Fast Recovery Epitaxial Diode (FRED)

V_{RRM} = 600 V
I_{FAVM} = 37 A
t_{rr} = 35 ns

| V _{RSM} V | V _{RRM} V | Type |
|-----------------------|-----------------------|--------------|
| 600 | 600 | DSEI 36-06AS |



TO-263 AB



A = Anode, C = Cathode, TAB = Cathode

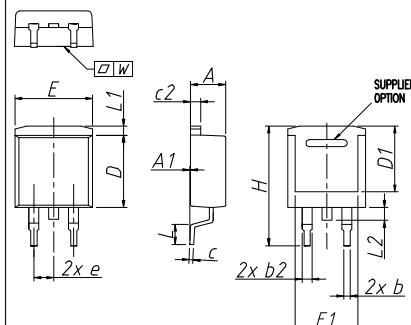
| Symbol | Test Conditions | Maximum Ratings | |
|---------------------|--|-----------------|------------------|
| I _{FRMS} ① | T _{VJ} = T _{VJM} | 70 | A |
| I _{FAVM} | T _C = 85°C; rectangular, d = 0.5 | 37 | A |
| I _{FRM} | t _p < 10 µs; rep. rating, pulse width limited by T _{VJM} | 375 | A |
| I _{FSM} | T _{VJ} = 45°C; t = 10 ms (50 Hz), sine | 300 | A |
| | t = 8.3 ms (60 Hz), sine | 320 | A |
| | T _{VJ} = 150°C; t = 10 ms (50 Hz), sine | 260 | A |
| | t = 8.3 ms (60 Hz), sine | 280 | A |
| I ² t | T _{VJ} = 45°C | 450 | A ² s |
| | t = 10 ms (50 Hz), sine | 420 | A ² s |
| | T _{VJ} = 150°C; t = 10 ms (50 Hz), sine | 340 | A ² s |
| | t = 8.3 ms (60 Hz), sine | 320 | A ² s |
| T _{VJ} | | -40...+150 | °C |
| T _{VJM} | | 150 | °C |
| T _{stg} | | -40...+150 | °C |
| P _{tot} | T _C = 25°C | 125 | W |
| Weight | | 2 | g |

| Symbol | Test Conditions | Characteristic Values | |
|-------------------|--|-----------------------|------|
| | | typ. | max. |
| I _R | T _{VJ} = 25°C V _R = V _{RRM} | 100 | µA |
| | T _{VJ} = 25°C V _R = 0.8 • V _{RRM} | 50 | µA |
| | T _{VJ} = 125°C V _R = 0.8 • V _{RRM} | 7 | mA |
| V _F | I _F = 37 A; T _{VJ} = 150°C | 1.4 | V |
| | T _{VJ} = 25°C | 1.6 | V |
| V _{TO} | For power-loss calculations only | 1.01 | V |
| r _T | T _{VJ} = T _{VJM} | 7.1 | mΩ |
| R _{thJC} | | 1.0 | K/W |
| t _{rr} | I _F = 1 A; -di/dt = 100 A/µs; V _R = 30 V; T _{VJ} = 25°C | 35 | ns |
| I _{RM} | V _R = 350 V; I _F = 30 A; -di _F /dt = 240 A/µs | 10 | 11 |
| | L ≤ 0.05 µH; T _{VJ} = 100°C | | A |

① I_{FAVM} rating includes reverse blocking losses at T_{VJM}; V_R = 0.8 V_{RRM}, duty cycle d = 0.5

Data according to IEC 60747

TO-263 AB Outline



| Dim. | Millimeter | | Inches | |
|------|--------------|-------|----------------|--------|
| | min | max | min | max |
| A | 4.06 | 4.83 | 0.160 | 0.190 |
| A1 | typ. 0.10 | | typ. 0.004 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 |
| b2 | 1.14 | 1.40 | 0.045 | 0.055 |
| c | 0.40 | 0.74 | 0.016 | 0.029 |
| c2 | 1.14 | 1.40 | 0.045 | 0.029 |
| D | 8.38 | 9.40 | 0.330 | 0.370 |
| D1 | 8.00 | 8.89 | 0.315 | 0.350 |
| E | 9.65 | 10.41 | 0.380 | 0.410 |
| E1 | 6.22 | 8.20 | 0.245 | 0.323 |
| e | 2.54 BSC | | 0.100 BSC | |
| H | 14.61 | 15.88 | 0.575 | 0.625 |
| L | 1.78 | 2.79 | 0.070 | 0.110 |
| L1 | 1.02 | 1.68 | 0.040 | 0.066 |
| L2 | 1.02 | 1.52 | 0.040 | 0.060 |
| W | typ. 0.02 | 0.040 | typ. 0.0008 | 0.0016 |

All dimensions conform with and/or are within JEDEC standard.

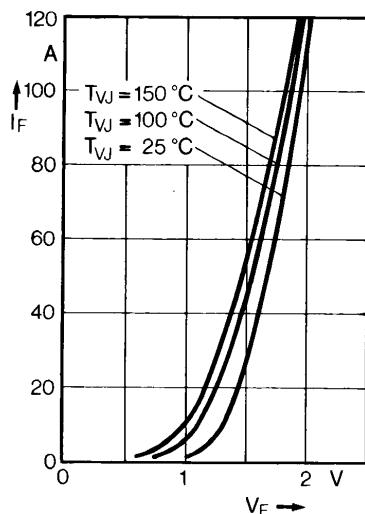


Fig. 1 Forward current versus voltage drop.

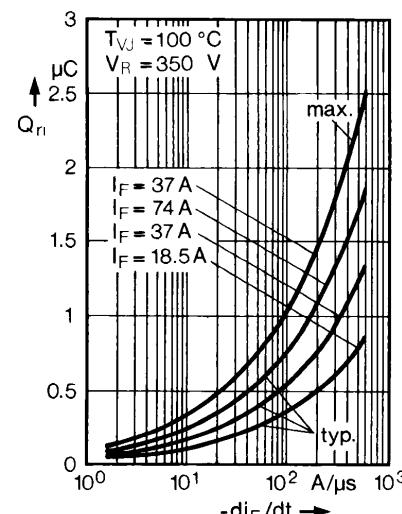


Fig. 2 Recovery charge versus $-di_F/dt$.

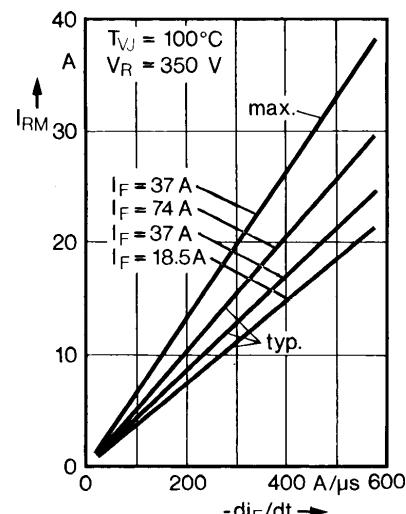


Fig. 3 Peak reverse current versus $-di_F/dt$.

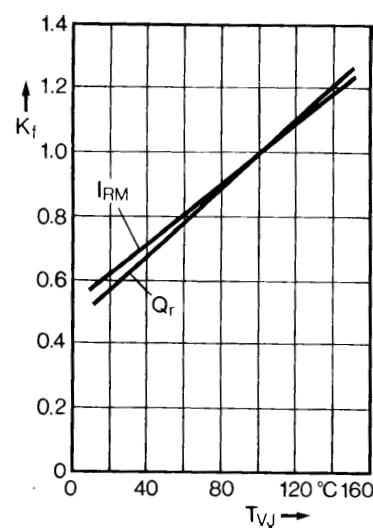


Fig. 4 Dynamic parameters versus junction temperature.

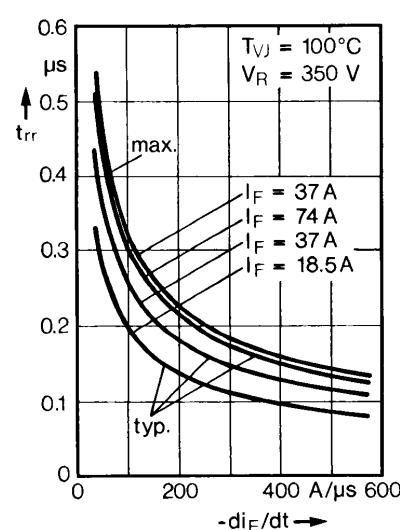


Fig. 5 Recovery time versus $-di_F/dt$.

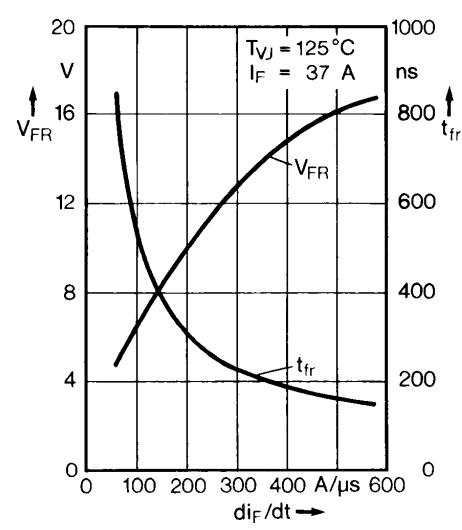


Fig. 6 Peak forward voltage versus di_F/dt .

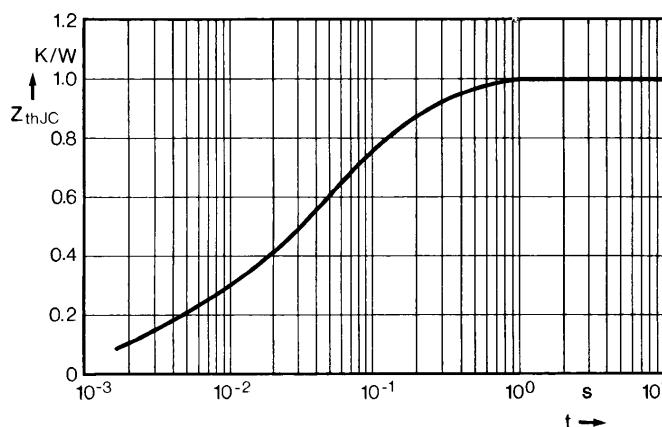


Fig. 7 Transient thermal impedance junction to case.